

Specific plateaus of the quantum Hall effect induced by an applied bias.

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Abstract

The spectrum and the eigenstates of a finite 2D tight-binding electronic system, with Dirichlet boundary conditions, in magnetic field and external linear potential are studied. The eigenstates show an equipotential character and may cross the plaquette in the direction perpendicular to the electric field. When leads are added to the plaquette, the channels carrying the current may be shortcut by equipotentials, resulting in additional plateaus situated inbetween the usual IQHE plateaus. This idea is confirmed by a numerical calculation within the four-terminal Landauer-Büttiker approach.

73.20Dx, 73.23.-b, 73.40.Hm

The Hofstadter spectrum, characteristic to an ordered plaquette with periodic boundary conditions along both directions (torus geometry) and a rational magnetic flux through the unit cell, shows well-defined gaps specified by the gap quantum numbers (s, σ) satisfying a Diophantine equation [1]. When Dirichlet boundary conditions are imposed along one direction (cylinder geometry), the gaps get filled with edge states. However, as long as the density of edge states is small compared to the density of band states, the gaps can be clearly observed (except eventually in the center of the spectrum) and we shall call them quasi-gaps. In both situations, when the Fermi energy lies in a (quasi-)gap, the Hall conductance is quantized and can be expressed either as a topological invariant described by σ or as a winding number of the edge states [2]. Introducing now Dirichlet boundary conditions all around the plaquette the qualitative aspect of the spectrum is preserved, although the edge states in quasi-gaps are denser. Fig.1 shows a quarter of the Hofstadter butterfly in this latter case. The usual topological arguments do not hold any more for the discussion of the Hall effect. We shall make use of a numerical calculation, based on the Landau-Büttiker formalism with four terminals. For the ordered plaquette, the Hall and the longitudinal resistances still show the typical plateaus of the IQHE, their accuracy being determined by the size of the system, and by the number of channels supported by the leads (see later in Fig.7).

The energy spectrum may be strongly affected by an applied bias; as expected, the tendency is to close the gaps, as it can be seen in Fig.2, where only a reminiscent quasi-gap can be observed. To some extent, this effect is similar to that of the disorder, although the mechanisms are different. Indeed, with increasing disorder the bands become wider and eventually the gaps disappear. In the disordered case, the presence of the (quasi-)gaps is necessary for the existence of the IQHE. The current is carried by the edge states, while the band states become localized, with a fractal structure, leading to fluctuations of the Hall resistance [3].

In this paper we shall show that, when an external bias is applied, Hall plateaus may exist even in the absence of quasi-gaps. The eigenstates have an equipotential character, i.e.

they are localized along the equipotential lines of the external potential, and this is sufficient to give rise to plateaus and also to new effects at the transition between them.

Let us consider a 2D square lattice with N sites in the x direction and M sites in the y direction (lattice constant=1). The one-electron problem defined on this plaquette in the presence of a perpendicular magnetic field is described by the following tight-binding Hamiltonian [1]:

$$H^S = \sum_{n=1}^N \sum_{m=1}^M [\epsilon_{nm} |n, m\rangle \langle n, m| + e^{i2\pi\phi m} |n, m\rangle \langle n+1, m| + |n, m\rangle \langle n, m+1| + h.c.], \quad (0.1)$$

$|n, m\rangle$ being a set of orthonormal states localized at the sites (n, m) , and ϕ the magnetic flux through the unit cell measured in quantum flux units ϕ_0 . The external linear potential is simulated by choosing the diagonal matrix elements of the form :

$$\epsilon_{nm} = dV (n - N/2), \quad n = 1, \dots, N.$$

Before addressing the problem of transport coefficients, it is useful to mention that, according to the invariance properties of the Hamiltonian (1), the eigenvalues have the obvious symmetries : i) $E_p(\phi) = E_p(-\phi)$, ii) $E_p(\phi) = E_p(\phi + 1)$, and iii) both E_p and $-E_p$ belong to the spectrum. Therefore the energy spectrum can be reduced to only a quarter of the Hofstadter butterfly. Of special interest is the spacial distribution of the eigenstates on the plaquette, at various energies, for $dV \neq 0$. An overall view can be obtained looking at the projection of all eigenvectors on a line crossing the plaquette along the x direction (which is the direction of the applied electric field), i.e. $|\langle n, m | \Psi_E \rangle|^2$, for $n = 1, \dots, N$ and a fixed m . An exemplification is given in Fig.3 for $\phi = 0.15$.

One has to notice that the localization of the eigenvectors on the plaquette depends both on the energy and on the applied potential:

a) At high energies the eigenvectors have a rectangular shape, with three sides on the borders of the plaquette (at $y = 0$, $y = M$, and $x = N$) and the fourth on an equipotential line at $x = N - \Delta n$, with $\Delta n = \Delta E / dV$, ΔE being the energy measured downwards, from the upper edge of the spectrum, at the given flux. Such edge states are thus shortcut by the

equipotentials of the external field, and may be called 'inner edge states'. The corresponding localization probability, $|\Psi|^2$, over the whole plaquette, is displayed in Fig.5a.

b) With decreasing energy the fourth side sweeps the plaquette until it touches the border at $x = 0$, and a true edge state is recovered.

c) At still lower energies a second band of equipotentials appears, which overlaps with the third and so on, and consequently there are no other gaps in the spectrum. In the second band, beside eigenvectors of the aspect shown in Fig.5a, there is also another type of eigenvector : it follows the edges all around the plaquette, but exhibits a ridge that connects the opposite sides of the plaquette in the y direction (see Fig.5b). This ridge moves with the energy and is also equipotential-type.

d) in the middle of the spectrum the states become blurred and we shall not analyze this region.

Now, we want to study the influence of the equipotential character of the eigenvectors on the transport properties of our plaquette. At this point, we need to remind of Büttiker's approach to the IQHE in multi-lead mesoscopic systems. Such a system is characterized by a conductance matrix $g_{\alpha\beta}$, relating the currents I_α to the potentials at the leads V_β :

$$\begin{aligned} I_\alpha &= \sum_{\beta} g_{\alpha\beta} V_\beta, \\ \sum_{\alpha} g_{\alpha\beta} &= \sum_{\beta} g_{\alpha\beta} = 0. \end{aligned} \tag{0.2}$$

We consider here a 4-lead system ($\alpha, \beta = 1, \dots, 4$), of the type sketched in Fig.4, and we denote by $n = integer$ the number of open channels that connect only the nearest leads in the sense of the current. The IQHE is generated by the matrix [4]

$$g_0 = \begin{pmatrix} -n & 0 & 0 & n \\ n & -n & 0 & 0 \\ 0 & n & -n & 0 \\ 0 & 0 & n & -n \end{pmatrix}.$$

The longitudinal and Hall resistances are given (in units of h/e^2) by

$$\begin{aligned}
R_L &= R_{14,23} = (g_{24}g_{31} - g_{21}g_{34})/D, \\
R_H &= (R_{13,24} - R_{24,13})/2 \\
&= (g_{23}g_{41} - g_{21}g_{43} - g_{32}g_{14} + g_{12}g_{34})/2D,
\end{aligned} \tag{0.3}$$

where D is a positive 3x3 subdeterminant of the matrix g_0 . Indeed, for the matrix g_0 one gets $R_L = 0$ and $R_H = 1/n$.

We shall look now for the effect of the external bias on the conductance matrix. We anticipate the idea that the ridges of the equipotentials (shown in Fig.5a and b) may shortcut at least one of the channels carrying the current around the plaquette. The result will depend essentially on the position where the shortcut occurs, namely :

a) If the equipotential sits between the leads no.1 and no.2, then the lead no.2 becomes connected to the lead no.4 (via the edge opposite to the leads) and, instead of $g_{24} = 0$ as in g_0 , one has $g_{24} = 1$. The sum-rule (2) will then automatically determine the whole matrix g_a :

$$g_a = \begin{pmatrix} -n & 0 & 0 & n \\ n & -n-1 & 0 & 1 \\ 0 & n+1 & -n-1 & 0 \\ 0 & 0 & n+1 & -n-1 \end{pmatrix}.$$

b) If the equipotential sits between the leads no.2 and no.3, then the lead no.3 will be connected to the lead no.4 and, instead of $g_{34} = 0$, one has $g_{34} = 1$. The new matrix will be g_b :

$$g_b = \begin{pmatrix} -n & 0 & 0 & n \\ n & -n & 0 & 0 \\ 0 & n & -n-1 & 1 \\ 0 & 0 & n+1 & -n-1 \end{pmatrix}.$$

Using Eqs.(3) one immediately gets for these two situations:

$$a) \quad R_L = 0, \quad R_H = \frac{1}{n+1}, \tag{0.4}$$

and

$$b) \quad R_L = \frac{1}{n(n+1)}, \quad R_H = \frac{1}{2} \left(\frac{1}{n} + \frac{1}{n+1} \right). \quad (0.5)$$

The result a) suggests that the edge states are not strictly necessary for the occurrence of IQHE; the equipotentials which do not touch all edges, but give the matrix g_a , are equally good. The result b) shows that, for energies corresponding to the equipotential states situated in the middle of the plaquette, intermediate plateaus should appear in the Hall resistance at $3/4, 5/12, 7/24, \dots$, but also in the longitudinal one at $1/2, 1/6, 1/12, \dots$.

The heuristic results (4) and (5) will be checked numerically in what follows. In order to calculate the transport coefficients (Hall and longitudinal resistance) we have to supplement the Hamiltonian (1) with terms describing the leads and the contacts. In our tight-binding model, each lead consists of n_c one-dimensional, semi-infinite perfect chains, stuck to the plaquette at consecutive sites. The chains may or may not be interconnected by a hopping term in the Hamiltonian. In the first situation, the Hamiltonian of the lead α reads

$$H_\alpha^L = t_L \sum_{\nu=1}^{n_c} \sum_{n \geq 1} [|\alpha, \nu, n\rangle \langle \alpha, \nu, n+1| + h.c.]. \quad (0.6)$$

Then, the Landauer-Büttiker formalism can be used for the calculation of the conductance matrix $g_{\alpha\beta}$. This may be expressed in terms of the scattering amplitude and calculated by the Green function technique:

$$g_{\alpha\beta} = \frac{e^2}{h} T_{\alpha\beta} = \frac{e^2}{h} \sum_{\nu, \nu'} |t_{\alpha\nu, \beta\nu'}|^2, \quad \alpha \neq \beta \quad (0.7)$$

where $t_{\alpha\nu, \beta\nu'}$ is the amplitude of the out-wave through the lead α and the channel ν when the in-wave is sent through β, ν' . The Green function formalism used for calculating the transmission coefficients is described in Ref.5.

The numerical results for the Hall and longitudinal resistances, in the presence of both magnetic and electric fields, are shown in Fig.6. It is known that the regions near the plateau transitions are the most sensitive to perturbations and, for instance, in the case of disordered samples, mesoscopic fluctuations may appear [6]. The same regions are influenced by the external bias, and the new plateaus appear not only in the Hall resistance but also in the

longitudinal one. For comparison, the Hall resistance in the absence of the bias is shown in Fig.7. Although the new plateaus are not very accurate, we want to stress that their values are very close to those predicted by Eqs.(4-5). The matrices g_a and g_b correspond to ideal contacts. Although the numerical data show that this is not the case, the results prove stable with respect to the deviation from the ideal matrices. The width of the intermediate plateaus increases with the applied potential. Indeed, the equipotential line sweeps the space δn between lead no.3 and lead no.2 in an energy interval $\delta E = dV \delta n$. However, when the potential becomes of the order of the bandwidth the picture breaks down.

The experimental results of Cobden and Kogan can be well described by the tight-binding model used in this paper [7], and this is why we think the effect predicted here, in the presence of an applied bias, should also be observable, for samples in which the FQHE is prevented by disorder or thermal effects. Since the new plateaus occur at small magnetic fluxes, we believe they should not be intrinsically related to the discrete structure of our plaquette.

In conclusion, the tight-binding approximation of the 2D lattice gas in crossed magnetic and electric fields shows specific spectral and transport properties in the quantum Hall regime. The electric field proves a useful tool, suitable to evidence inner edge states.

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FIGURES

FIG. 1. The spectrum as function of magnetic flux (in units ϕ_0): Dirichlet boundary conditions along both directions ($N = 64, M = 10$)

FIG. 2. The spectrum as function of magnetic flux in the presence of an applied external potential ($dV = 0.02, N = 64, M = 10$).

FIG. 3. Eigenvectors projected along a line parallel to the electric field ($dV = 0.02, \phi = 0.15, N = 64, M = 10$).

FIG. 4. Plaquette with four terminals.

FIG. 5. $|\Psi|^2$ on whole plaquette for: a) $E=3.1495$ and b) $E=2.3298$ ($dV = 0.02, \phi = 0.1, N = 64, M = 10$).

FIG. 6. Hall (full line) and longitudinal (dashed line) resistance as function of energy in the presence of external bias : $\phi = 0.10, dV = 0.02, N = 64, M = 10$. The values predicted by Eqs.(4-5) are indicated by horizontal lines. (resistances are in units h/e^2)

FIG. 7. Hall resistance (in units h/e^2) as function of energy in the absence of external bias : $\phi = 0.10, dV = 0.0, N = 64, M = 10$.

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